### BAS21HT1

**Preferred Device** 

## High Voltage Switching Diode

• Device Marking: JS



http://onsemi.com

# HIGH VOLTAGE SWITCHING DIODE

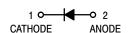


SOD-323 CASE 477 PLASTIC

#### **MARKING DIAGRAM**



JS = Device Code



#### **ORDERING INFORMATION**

Device	Package	Shipping
BAS21HT1	SOD-323	3000/Tape & Reel

**Preferred** devices are recommended choices for future use and best overall value.

#### **MAXIMUM RATINGS**

Symbol	Rating	Value	Unit
V <sub>R</sub>	Continuous Reverse Voltage	250	Vdc
lF	Peak Forward Current	200	mAdc
I <sub>FM(surge)</sub>	I <sub>FM(surge)</sub> Peak Forward Surge Current		mAdc

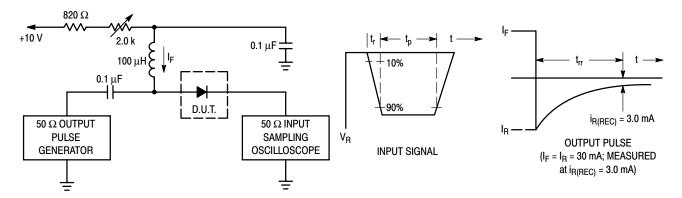
#### THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
P <sub>D</sub>	Total Device Dissipation FR–5 Board,*  T <sub>A</sub> = 25°C		mW
	Derate above 25°C		mW/°C
$R_{\theta JA}$	Thermal Resistance Junction to Ambient		°C/W
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature Range	-55 to +150	ô

<sup>\*</sup>FR-5 Minimum Pad

**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current $(V_R = 200 \text{ Vdc})$ $(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I <sub>R</sub>	_ _	0.1 100	μAdc
Reverse Breakdown Voltage (I <sub>BR</sub> = 100 μAdc)	V <sub>(BR)</sub>	250	-	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc) (I <sub>F</sub> = 200 mAdc)	V <sub>F</sub>	_ _	1000 1250	mV
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)	C <sub>D</sub>	-	5.0	pF
Reverse Recovery Time $(I_F = I_R = 30 \text{ mAdc}, R_L = 100 \Omega)$	t <sub>rr</sub>	-	50	ns



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 30 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.
- 3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit

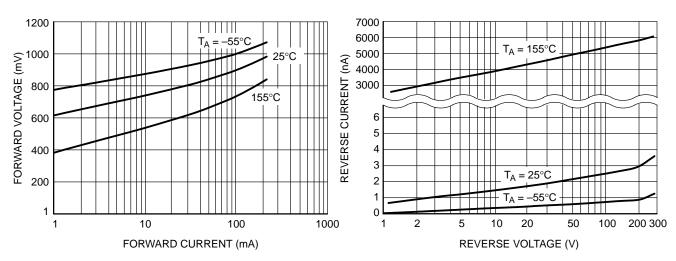
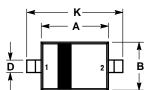


Figure 2. Forward Voltage

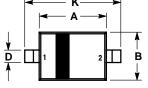
Figure 3. Reverse Leakage

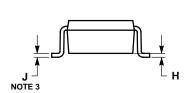
#### BAS21HT1

#### **PACKAGE DIMENSIONS**



SOD-323 PLASTIC PACKAGE CASE 477-02 **ISSUE A** 







- NOTES:

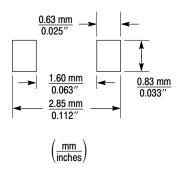
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.60	1.80	0.063	0.071
В	1.15	1.35	0.045	0.053
C	0.80	1.00	0.031	0.039
D	0.25	0.40	0.010	0.016
Е	0.15 REF		0.006	REF
Н	0.00	0.10	0.000	0.004
J	0.089	0.177	0.0035	0.0070
K	2.30	2.70	0.091	0.106

STYLE 1: PIN 1. CATHODE 2. ANODE



SOD-323 Soldering Footprint

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